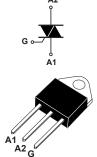


# 25 A standard Triacs in TOP3 package



**TOP3** Insulated

#### **Features**

On-state current (I<sub>T(RMS)</sub>): 25 A

Max. blocking voltage (V<sub>DRM</sub>/V<sub>RRM</sub>): 1200 V

Gate current (I<sub>GT</sub>): 150 mA

Commutation at 10 V/µs: up to 88 A/ms

Noise immunity: 2 kV/µs

Insulated package:

2500 V rms (UL recognized: E81734)

#### **Application**



Motor starter

Induction motor speed control



Product status link
TPDV825RG
TPDV1025RG
TPDV1225RG

TPDV825RG
TPDV1025RG
TPDV1225RG

11 DV 122310					
Product summary					
I <sub>T(RMS)</sub> 25 A					
	TPDV825RG: 825 V				
$V_{DRM}/V_{RRM}$	TPDV1025RG: 1025 V				

 $I_{GT}$ 

TPDV1225RG: 1225 V 150 mA

### **Description**

The TPDVxx25 series use high performance alternistor technology.

Featuring very high commutation levels and high surge current capability, these devices are well adapted to power control for inductive and resistive loads (motor, transformer...) especially on three-phase power grid. Targeted three-phase applications include heating systems, motor starters, and induction motor speed control (especially for fans).



# 1 Characteristics

Table 1. Absolute maximum ratings (limiting values)

Symbol		Parameters			Unit
I <sub>T(RMS)</sub>	RMS on-state currer angle)	nt (180° conduction	T <sub>c</sub> = 85 °C	25	А
	Non repetitive	t <sub>p</sub> = 2.5 ms		390	
I <sub>TSM</sub>	surge peak on-	t <sub>p</sub> = 8.3 ms	T <sub>j</sub> = 25 °C	250	Α
	state current	t <sub>p</sub> = 10 ms		230	-
I <sup>2</sup> t	I <sup>2</sup> t value for fusing	t <sub>p</sub> = 10 ms	T <sub>j</sub> = 25 °C	265	A <sup>2</sup> s
dl/dt	Critical rate of rise of on-state current I <sub>G</sub> = 500 mA, dI <sub>G</sub> /dt = 1 A/µs	f = 50 Hz		100	A/µs
	V <sub>DRM</sub> , V <sub>RRM</sub> Repetitive surge peak off-state voltage	TPDV825		800	
$V_{DRM}, V_{RRM}$		TPDV1025	T <sub>j</sub> = 125 °C	1000	V
		TPDV1225		1200	
I <sub>GM</sub>	Peak gate current			8	А
$P_{GM}$	Peak gate power dissipation	t <sub>p</sub> = 20 μs	t <sub>p</sub> = 20 μs		W
$V_{GM}$	Peak positive gate voltage			16	V
P <sub>G(AV)</sub>	Average gate power	dissipation		1	W
T <sub>stg</sub>	Storage junction tem	mperature range		-40 to +150	°C
Tj	Operating junction to	erating junction temperature range			°C
V <sub>INS</sub> <sup>(1)</sup>	Insulation RMS volta	nsulation RMS voltage, 1 minute			V

<sup>1.</sup> A1, A2, gate terminals to case for 1 minute.

Table 2. Electrical characteristics ( $T_j = 25$  °C, unless otherwise specified)

Symbol	Parameters		Value	Unit	
I <sub>GT</sub> <sup>(1)</sup>	$V_D = 12 \text{ V}, R_L = 33 \Omega$	Max.	150	mA	
V <sub>GT</sub>	VD - 12 V, NL - 33 12	1 - 11 - 111	Max.	1.5	V
V <sub>GD</sub>	$V_D = V_{DRM}, R_L = 3.3 \text{ k}\Omega, T_j = 125 \text{ °C}$	1 - 11 - 111	Min.	0.2	V
t <sub>GT</sub>	$V_D = V_{DRM}$ , $I_G = 500$ mA, $dI_G/dt = 3$ A/ $\mu$ s	Тур.	2.5	μs	
IH <sup>(2)</sup>	I <sub>T</sub> = 500 mA	Тур.	50	mA	
ΙL	I <sub>G</sub> = 1.2 I <sub>GT</sub>	I - III	Тур.	100	mA
"	16 - 1.2 161	II	Тур.	200	IIIA
dV/dt <sup>(2)</sup>	$V_D = 67 \% V_{DRM}$ gate open, $T_j = 125 \degree C$	Min.	2000	V/µs	
(d1/dt)o(2)	$ (dI/dt)c^{(2)} $ $ (dI/dt)c = 200 \text{ A/ms, T}_j = 125 \text{ °C} $ $ (dI/dt)c = 10 \text{ A/ms, T}_j = 125 \text{ °C} $				A/ms
(ui/ut)c(=)					

<sup>1.</sup> Minimum  $I_{GT}$  is guaranteed at 5 % of  $I_{GT}$  max.

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<sup>2.</sup> For both polarities of A2 referenced to A1



#### **Table 3. Static electrical characteristics**

Symbol	Test conditions	Tj	Value	Unit
V <sub>TM</sub> <sup>(1)</sup>	$I_{TM} = 35 \text{ A}, t_p = 380  \mu\text{s}$	25 °C	1.8	V
V <sub>TO</sub> <sup>(1)</sup>	threshold on-state voltage	125 °C	1.1	V
R <sub>D</sub> <sup>(1)</sup>	Dynamic resistance	125 °C	19	mΩ
I <sub>DRM</sub> /I <sub>RRM</sub>	V <sub>DRM</sub> = V <sub>RRM</sub>	25 °C	20	μA
	VDRM - VRRM	125 °C	8	mA

1. For both polarities of A2 referenced to A1

**Table 4. Thermal resistance** 

Symbol	Parameters	Value	Unit
P.,	Junction to case (DC)	1.5	
$R_{th(j-c)}$	Junction to case (AC) for 360 ° conduction angle (F = 50 Hz)	1.1	°C/W
R <sub>th(j-a)</sub>	Junction to ambient	50	

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#### 1.1 Characteristics (curves)

Figure 1. Max. rms power dissipation versus on-state rms current (F = 50Hz, curves limited by (dl/dt)c)

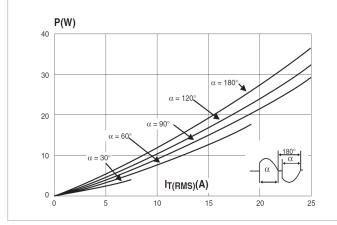


Figure 2. Max. rms power dissipation and max. allowable temperatures ( $T_{amb}$  and  $T_{case}$ ) for various  $R_{th}$ 

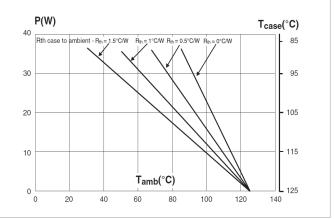


Figure 3. On-state rms current versus case temperature

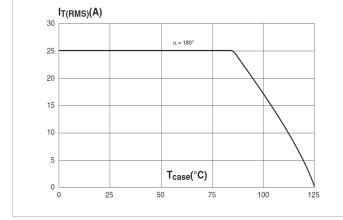


Figure 4. Relative variation of thermal impedance versus pulse duration

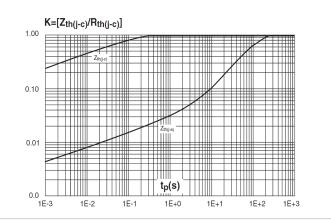


Figure 5. Relative variation of gate trigger current and holding current versus junction temperature

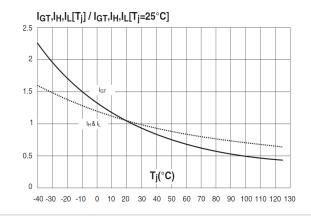
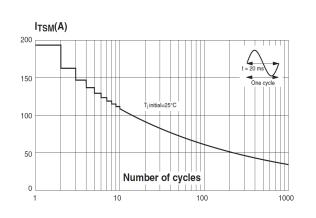


Figure 6. Non-repetitive surge peak on-state current versus number of cycles



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Figure 7. Non-repetitive surge peak on-state current for a sinusoidal pulse and corresponding values of l²t

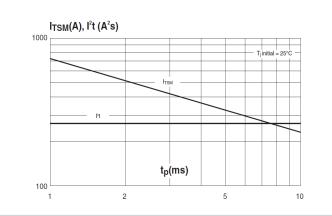


Figure 8. On-state characteristics (maximum values)

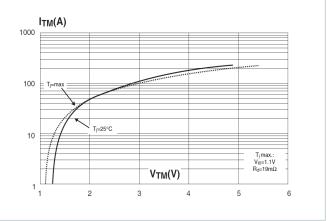
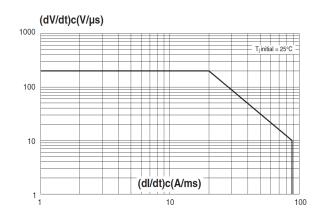


Figure 9. Safe turn-off operating area



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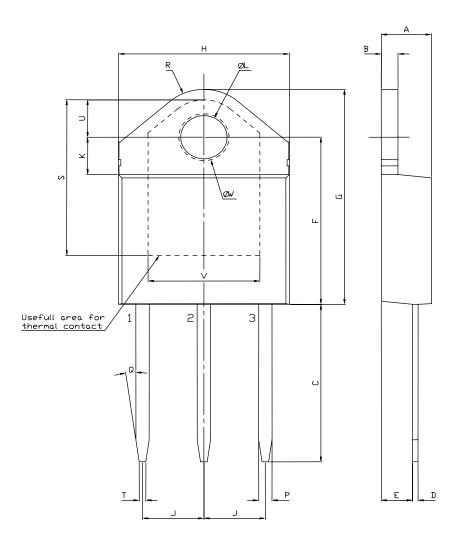
# Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

#### 2.1 Package information

- ECOPACK (lead-free plating and halogen free package compliance)
- Lead-free package leads finishing
- Halogen-free molding compound resin meets UL94 standard level V0
- Recommended torque: 1.05 N·m (max. torque: 1.2 N·m)

Figure 10. Package outline



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Table 5. Mechanical data

	Dimensions						
Ref.		mm			Inches <sup>(1)</sup>		
	Min.	Тур.	Max.	Min.	Тур.	Max.	
Α	4.40		4.60	0.1732		0.1811	
В	1.45		1.55	0.0571		0.0610	
С	14.35		15.60	0.5650		0.6142	
D	0.50		0.70	0.0197		0.0276	
Е	2.70		2.90	0.1063		0.1142	
F	15.80		16.50	0.6220		0.6496	
G	20.40		21.10	0.8031		0.8307	
Н	15.10		15.50	0.5945		0.6102	
J	5.40		5.65	0.2126		0.2224	
K	3.40		3.65	0.1339		0.1437	
L	4.08		4.17	0.1606		0.1642	
Р	1.10		1.30	0.0430		0.0510	
R		4.60			0.1811		

<sup>1.</sup> Inches given for reference only

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# 3 Ordering information

Table 6. Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
TPDV825RG	TPDV825				
TPDV1025RG	TPDV1025	TOP3 Ins.	3 Ins. 4.5 g	30	Tube
TPDV1225RG	TPDV1225				

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# **Revision history**

Table 7. Document revision history

Date	Revision	Changes
30-Mar-2011	1	First issue.
13-Jan-2012	2	Updated dl/dt in <i>Table 2</i> and added V <sub>to</sub> and R <sub>d</sub> to <i>Table 3</i> .
06-Oct-2023	3	Updated Section 2.1 Package information.

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